

ITJV01500A2C^{V0}*2 Class AB 108MHz

Mar 26, 2026

Introduction

This amplifier is designed with Innogrations 50V LDMOS transistor.

Demo and Transistor

Frequencyband	: 108MHz
Application	: Multi Market
Configuration	: Class AB
Test Signal	: CW/Pulse
Transistor	: ITJV01500A2C ^{V0}
Date code	: 261219S
PCB	: Rogers tc350-plus

The amplifier has been characterized under the following conditions:

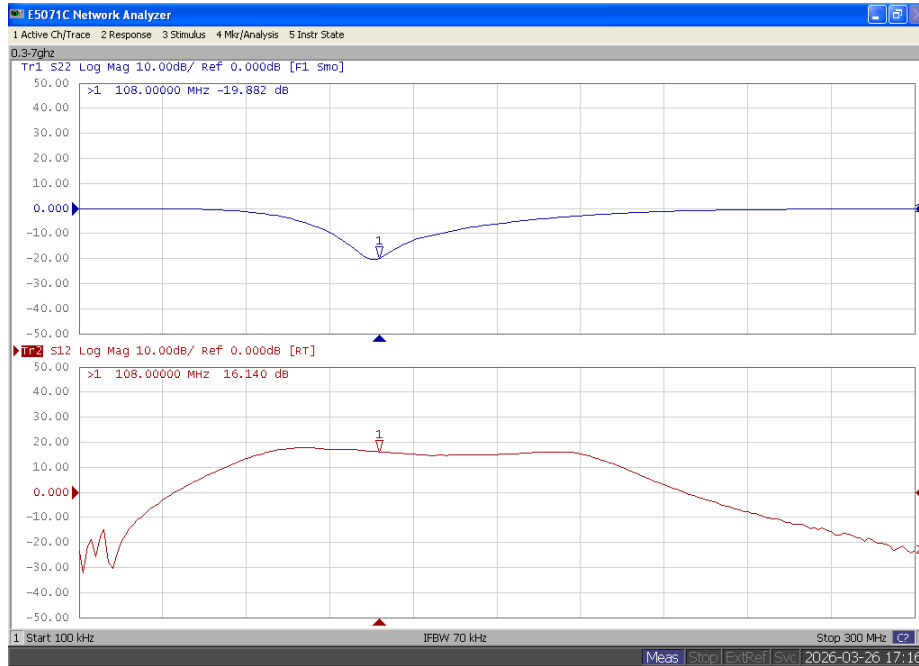
- Network Analyzer plots for gain and IRL.
- The output power measurement using CW / Pulse .

Note: The PA is tested with a supply voltage of $V_{DS} = 50V$, $I_{dq} = 200mA$, all measurements unless otherwise noted.

1. Network Results

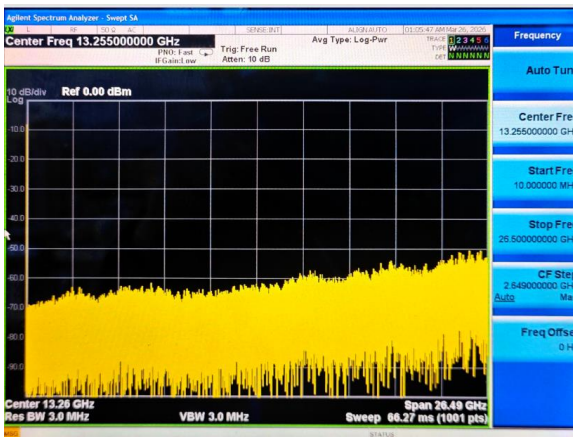
Test Condition

$V_{ds}=50V$, $V_{gs}=3.48V$, $I_{dq}=700mA$, Input Power = 0dBm



spectrum analyzer to • show no oscillation or instability issue

Test Condition: $V_{gs}= 3.6V$, $V_{ds}= 50V$, $I_{dq} = 1.7A$



Test Results

2. Summary @ Bench 2(SuZhou)

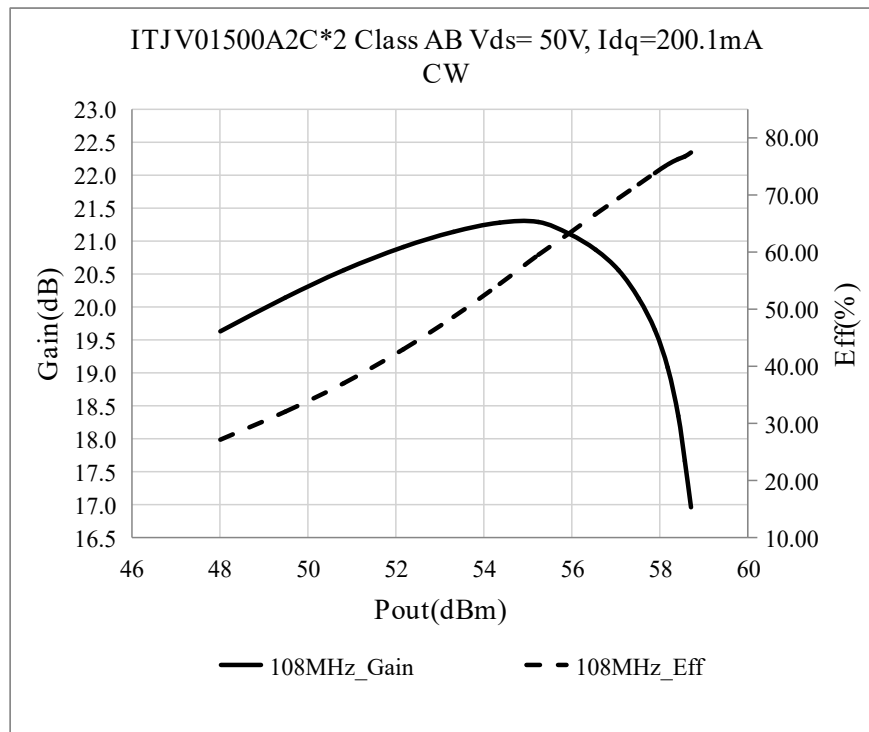
(1) Test Condition

Signal mode : CW

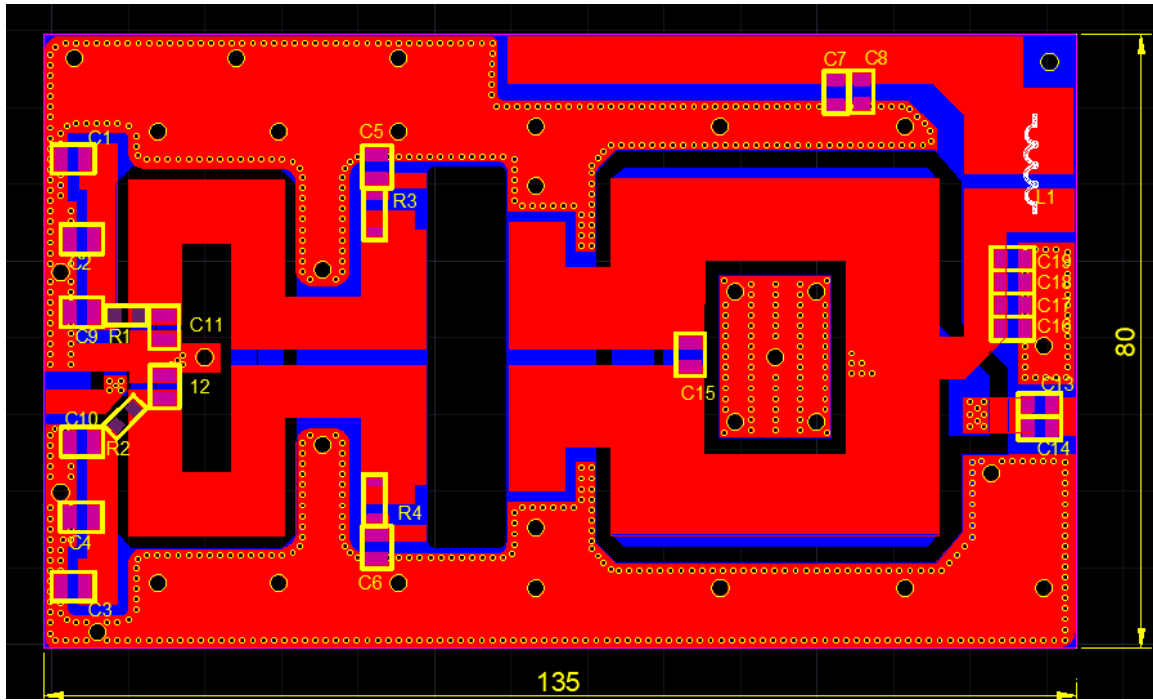
Frequency : 108MHz

$V_{gs} = 3.31V$, $V_{ds} = 50V$, $I_{dq} = 200mA$

Freq (MHz)	P1dB (dBm)	P1dB (W)	P1dB Eff (%)	P1dB Gain (dB)	P3dB (dBm)	P3dB (W)	P3dB Eff (%)
108	57.54	568.1	72.6	20.69	58.63	729.3	78.1



BOM of Test Circuit



Component	Description	Suggested Manufacturer
C1~C8	10uF/200V-1210	Ceramic multilayer capacitor
C9,C10	560pF	
C11,C12	510pF	
C13,C14,C16~C19	470pF	
C15	30pF	
R1,R2	300 Ω/1206	Chip Resistor
R3,R4	51 Ω 2512	Chip Resistor
L1	1.5mm wire, 5mm innerdiameter, 7turns	DIY

Demo Picture

LBG-26-12

ITJV01500A2C^{VO}: 108MHz

